Notes and News

Announcements and other items of crystallographic interest will be published under this heading at the discretion of the Editorial Board. The notes (in duplicate) should be sent to the Executive Secretary of the International Union of Crystallography (J. N. King, International Union of Crystallography, 13 White Friars, Chester CH1 1NZ, England).

New Volume of International Tables for X-ray Crystallography

Volume IV, entitled *Revised and Supplementary Tables* and edited by James A. Ibers and the late Walter C. Hamilton, has just been published for the Union by the Kynoch Press, Witton, Birmingham B6 7BA, England, at a price of £10.00. Orders may be placed direct with the Kynoch Press, with Polycrystal Book Service, P.O. Box 11567, Pittsburgh, Pa. 15238, U.S.A., or with any bookseller.

Since the publication of Volume III in 1962, experimental and theoretical activity in all areas of crystallography has greatly increased. The principle motivation for a new volume was to provide revised values for atomic scattering factors, X-ray wavelengths and atomic absorption coefficients.

Volume IV has a cumulative index for all four volumes. When specific information included in Volume IV supersedes material in an earlier volume, the reference to the earlier volume is included in parentheses. In such cases, the numerical values given in Volume IV should be used, but the earlier volume should also be consulted for the

sometimes extensive textual material accompanying the tables.

A number of special topics, mainly mathematical in content, which were not included in Volume II, have developed considerably and have been incorporatee in Volume IV. Such new material, selected by the Editors, includes diffractometer calculations, analysis of thermal motion in crystals, and some aspects of direct methods for phase determination. Although some of this material is more textual than tabular, it has been included because of its greater importance to most structural crystallographers. Omission of other topics should not be taken as indicative of their relative unimportance. Selection had to be made by the Editors. The Union is greatly indebted to the Editors and to all the contributing authors for making the publication of this volume possible.

Volumes I, II and III in this series are still available but it has been necessary to increase the slightly to £8.00 per volume. Prospectuses for all volumes and details of preferential prices for personal subscribers may be obtained from the Kynoch Press or from Polycrystal Book Service.

Book Reviews

Works intended for notice in this column should be sent direct to the Book-Review Editor (M. M. Woolfson, Physics Department, University of York, Heslington, York YO1 5DD, England). As far as practicable books will be reviewed in a country different from that of publication.

Solid state chemistry and physics – an introduction. Vol. 1. Edited by PAUL F. WELLER. Pp.xi + 500, Figs. 165, Tables 23. New York: Marcel Dekker, 1973. Price \$26.50.

Nothing short of Renaissance-quality versatility is nowadays required in order successfully to straddle the vast range of chemical, physical, mathematical and even biological knowledge currently encompassed by solid-state science. This fact would be accepted with more philosophical resignation were it not recognized that contemporary quantal and crystallographic interpretations of the behaviour of solids offer considerable academic exitement, and that the proper technological utilization of various electronic devices requires deep understanding of a variety of unrelated phenomena. A book such as that under review is therefore examined with more than usual thoroughness, particularly as a prospective text for graduate workers, for whom it is primarily intended.

Part I, sub-titled Concepts and Properties (pp. 186) serves as a relatively non-mathematical introduction to the concepts used throughout the remainder of the text. Part II, Physical Properties and Imperfections includes chapters on Electrical Properties of Solides (pp. 104) by Perlstein,

Magnetic Properties (pp. 60) by Steger, Magnetic Resonance (pp. 51) by Kasai and Optical Properties (pp. 88) by Axe. In Volume 2, yet to appear, Part II will be continued to deal with Point Defects, Diffusion and Surface Chemistry, and two further parts will deal with Purification and Crystal Growth, Polymeric Materials and Biology and Semiconduction.

On balance Volume I, especially the first three chapters, succeeds in what it sets out to achieve. The first chapter, by the editor, is a courageous and competent attempt to interrelate the various principles and concepts which are developed later. In some places, however, notably in discussions of the F-centre (p. 50) and application of crystal-field theory to the ruby laser (p. 57), more is promised than is actually delivered in Chapters 7 and 3 respectively. The section on Crystallography (Suchow), after summarizing material normally taught at a relatively elementary undergraduate level, includes a lucid account of the structural principles of related, simple inorganic solids (e.g. ReO, perovskite and tungsten bronze) and of stacking disorders and polytypism. It misses an opportunity, however, of linking dislocations (which are also very briefly considered) with stacking faults (in terms of partials) and thereby offering insights as to how some of the structural types considered earlier may be interconverted. Crowder's chapter (47 pp.) on *Bonding Models* contains a first-class treatment of elementary band theory, where the nearly-free electron theories and the tight-binding approximations are discussed. It is a pity that this chapter was not extended to deal with other aspects of energy-level diagrams, many of which (e.g. semiconductor characteristics) are deferred until they appear, rather unexpectedly, in the *Physical Properties and Imperfections* section.

Apart from relatively minor presentational infelicities – such as the use of the symbol n to mean three distinct properties within the space of two pages, (226–227), and a rather imprecise use of the term 'activation energy' (pp. 25 and 31) and the unreasonable deferment of the properties of point defects (which are needed anyway in Chapter 7, p. 488) until Volume 2 – this book has much to commend it. It should prove valuable both to the experimentalist and theoretician interested in solid-state phenomena.

Like so many modern scientific monographs it lacks a subject index, a regrettable omission.

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Electron optics. By P. GRIVET, translated by P. W. HAWKES and revised by A. SEPTIER. Pp.lvii + 870, Figs. 323. Oxford: Pergamon Press, 1972. Price£12.00.

It is now nine years since the first edition of Grivet appeared in English and it remains one of the best books on the subject today, treating as it does not only the principles of electron optics but also their application in the electron microscope and other instruments. In this new edition the chapters dealing with the calculation of the field and potential in both electrostatic and magnetic lenses have been considerably expanded. However, despite the 1972 publication date the powerful methods developed by Read are not mentioned. The emphasis of the book is on high-energy optics, but this is rarely explicit or obtrusive though the instrumental examples are all on high-energy devices. A complete chapter has been added on prism optics and this includes a discussion of the fringing field problem in both the magnetic and electrostatic cases. The treatment is fairly general, but does not mention some of the fairly recent advances in the use of parallel-plane or coaxialcylinder geometries nor the very important work of Purcell on spherical electrostatic systems.

An edition in two parts, *Optics* and *Instruments*, is available. For readers who are less interested in instruments there are possibly better, though more expensive, choices but for those who need the full coverage this book is excellent.

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Department of Physics Royal Holloway College University of London London England The use of the scanning electron microscope. By J.W. S. HEARLE, J.T. SPARROW and P. M. CROSS. Pp.x+278, Figs. 140, Tables 12. Oxford: Pergamon Press, 1972. Price £8.80.

Although written with the needs of the practising microscopist in mind this book is more than just a user's handbook. It contains some very good chapters on how to use a scanning microscope and how to prepare specimens for it, but it also contains chapters written by well-known experts in their fields describing the excellent use to which the microscope can be put in metallurgical science, biology, solid-state electronic-device technology and fibre technology. The book is therefore stimulating as well as informative. The breadth of coverage in these chapters on applications serves well to illustrate how widely the scanning microscope is now used in the study of materials. Such widespread use surely could not have been anticipated when the first commercial instruments were introduced only ten years ago.

The chapters describing the techniques for preparing specimens and how to examine them in the various scanning modes are excellently written. They provide clear instructions on the correct procedures to be followed and warn against the pitfalls arising from misuse. The chapters on applications are very comprehensive and well illustrated. In some cases, Applications to Metallurgy for example, the author provides a review of the use of scanning microscopy which is not readily available from any other source. There are also chapters dealing with the design of scanning microscopes and the interaction of electrons with solids. Whilst these are by no means exhaustive in their coverage, and are certainly not rigorous in treatment, they do nevertheless serve a useful purpose in providing the microscope user with the background to his art. The book concludes with a look at the future of scanning electron microscopy. This examines the current developments of the instrument towards higher resolution, using field-emission guns, greater sensitivity and consequently more rapid response to dynamic effects in the specimen, and the incorporation of X-ray and electron energy-loss analysis for element identification. It is likely that the next generation of scanning microscope will play a greater role in the quantitative analysis of materials.

This book provides very good reading. Although there are eight separate contributors it has been put together by the three editors to make a coherent text. It should appeal to a large number of users.

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Solid state chemistry and physics, Vol. 2. Edited by PAUL F. Weller. Pp.xi + 434, Figs. 111, Tables 21. New York: Marcel Dekker, 1974. Price \$25.75.

This is the second volume of an introduction to solid state physics and chemistry intended to give undergraduate or graduate students a broad interdisciplinary view of the field. It consists of seven separately authored chapters covering